



ifu 2814

Docket: 14466

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

First Named Inventor:	John P. Snyder	Examiner: PHAM, LONG
Appln. No.:	09/928,124	
Filed:	8/10/2001	
A fabrication method for a device for regulating flow of electric current with high dielectric constant gate insulating layer and source/drain forming Schottky contact or		
Title:	Schottky-like region with substrate	Group Art Unit: 2814

REVOCATION AND POWER OF ATTORNEY

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

I hereby certify that this document is being sent via First Class U.S. mail addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on this 31 day of July, 2004.

David J King
(Signature)

Sir:

In the above-referenced patent application, on behalf of Spinnaker Semiconductor, Inc. , I (we) hereby revoke(s) all previously-filed powers of attorney and appoint David J King, patent agent (Reg. no. 53,132) to prosecute the patent application identified above and to transact all business in the Patent and Trademark Office connected therewith, including full power of association, substitution, and revocation.

Please address all telephone calls to: David J King at (952) 223-5250.

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The undersigned (whose title is supplied below) is empowered to sign this statement on behalf of Spinnaker Semiconductor, Inc.

Dated: July 20, 2007

Signature: /Glenn Carter/

Name: Glenn Carter

Title: CEO